

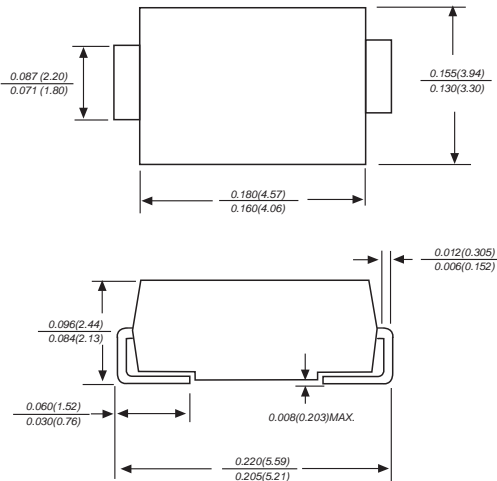


ES3A THRU ES3J

SURFACE MOUNT SUPER FAST RECTIFIER

Reverse Voltage - 50 to 600 Volts Forward Current - 3.0 Amperes

DO-214AA/SMB



Dimensions in inches and (millimeters)

FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Low reverse leakage
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 250°C/10 seconds at terminals
- ◆ Glass passivated chip junction

MECHANICAL DATA

Case: JEDEC DO-214AA molded plastic body
Terminals: leads solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.003 ounce, 0.093 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

| MDD Catalog Number | SYMBOLS | ES3A | ES3B | ES3C | ES3D | ES3E | ES3G | ES3J | UNITS |
|---|-----------------|--------------|------|------|------|------|------|------|--------------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | VOLTS |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 105 | 140 | 210 | 280 | 420 | VOLTS |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | VOLTS |
| Maximum average forward rectified current at $T_L=75^\circ\text{C}$ | $I_{(AV)}$ | 3.0 | | | | | | | Amps |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | 100.0 | | | | | | | Amps |
| Maximum instantaneous forward voltage at 3.0A | V_F | 0.95 | | | 1.25 | | 1.7 | | Volts |
| Maximum DC reverse current at rated DC blocking voltage $T_A=25^\circ\text{C}$ $T_A=100^\circ\text{C}$ | I_R | 5.0 100.0 | | | | | | | μA |
| Maximum reverse recovery time (NOTE 1) | t_{rr} | 35 | | | | | | | ns |
| Typical junction capacitance (NOTE 2) | C_J | 45.0 | | | | | | | pF |
| Typical thermal resistance (NOTE 3) | $R_{\theta JA}$ | 47.0 | | | | | | | $^\circ\text{C/W}$ |
| Operating junction and storage temperature range | T_J, T_{STG} | -50 to +150 | | | | | | | $^\circ\text{C}$ |

Note: 1. Reverse recovery condition $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$
 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 3. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

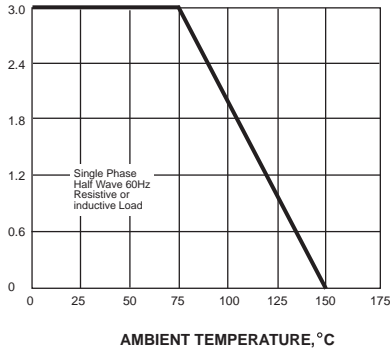


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RATINGS AND CHARACTERISTIC CURVES ES3A THRU ES3J

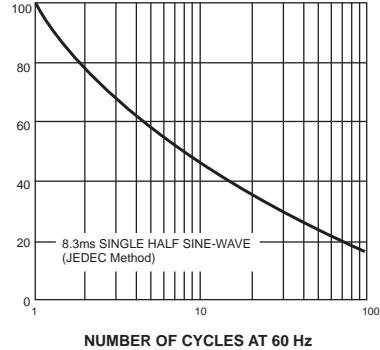
AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



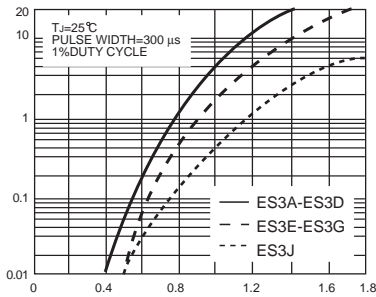
PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



INSTANTANEOUS FORWARD CURRENT, AMPERES

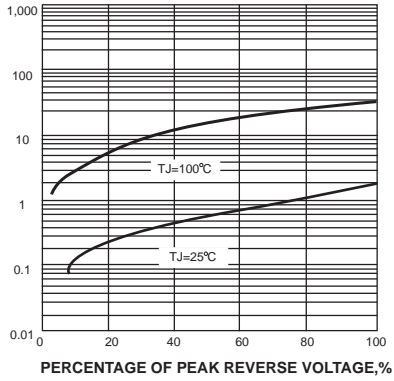
FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE,
VOLTS

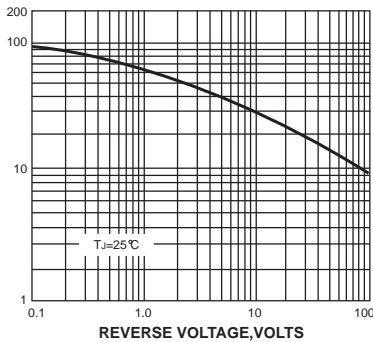
INSTANTANEOUS REVERSE CURRENT,
MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



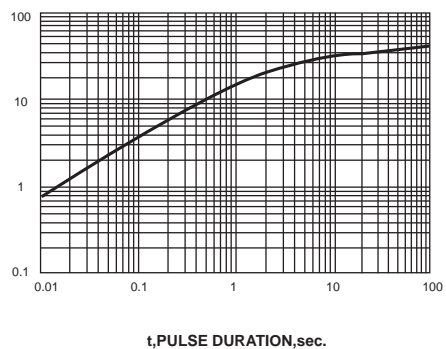
JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!

